

## Product Summary

$V_{(BR)DSS}$	$R_{DS(on)TYP}$	$I_D$
-30V	13mΩ@-10V	-16A
	22mΩ@-4.5V	

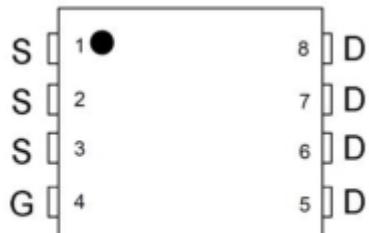
## Feature

- Enhancement mode
- Low on-resistance RDS(on)
- Pb-free lead plating; RoHS compliant

## Application

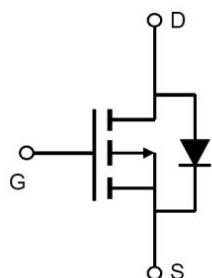
- Battery Switch
- Load switch
- Power management

## Package

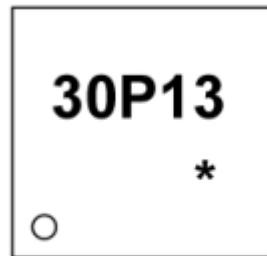


**PDFNWB3.3×3.3-8L**

## Circuit diagram



## Marking



**30P13 =Device Code**  
**\***      **=Month Code**

## Absolute maximum ratings

( $T_a=25^\circ\text{C}$  unless otherwise noted)

Parameter	Symbol	Value	Unit
Drain-Source Voltage	$V_{DS}$	-30	V
Gate-Source Voltage	$V_{GS}$	$\pm 20$	V
Drain Current-Continuous	$I_D$	-16	A
Pulsed Drain Current <sup>1)</sup>	$I_{DM}$	-64	A
Maximum Power Dissipation	$P_D$	33	W
Thermal Resistance from Junction to Ambient <sup>2)</sup>	$R_{\theta JA}$	3.8	$^\circ\text{C}$
Operating Junction and Storage Temperature Range	$T_J, T_{STG}$	-55~ +150	$^\circ\text{C}$

## Electrical characteristics

( $T_A=25^\circ\text{C}$ , unless otherwise noted)

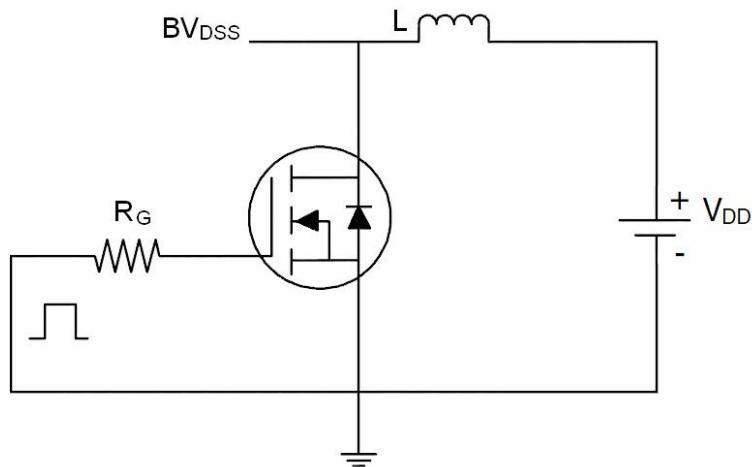
Parameter	Symbol	Test Condition	Min.	Typ.	Max.	Unit
<b>Static Characteristics</b>						
Drain-Source Breakdown Voltage	BV (BR)DSS	$V_{GS} = 0\text{V}, I_D = -250\mu\text{A}$	-30			V
Zero Gate Voltage Drain Current	$I_{DSS}$	$V_{DS} = -30\text{V}, V_{GS} = 0\text{V}$			-1	$\mu\text{A}$
Gate-Source Leakage	$I_{GSS}$	$V_{GS} = \pm 20\text{V}, V_{DS} = 0\text{V}$			$\pm 100$	$\mu\text{A}$
<b>On Characteristics</b> <small>(Note 3)</small>						
Gate Threshold Voltage	$V_{GS(\text{th})}$	$V_{DS} = V_{GS}, I_D = -250\mu\text{A}$	-1.2	-1.6	-2.5	V
Drain-Source On-Resistance <sup>1</sup>	$R_{DS(\text{on})}$	$V_{GS} = -10\text{V}, I_D = -20\text{A}$		13	18	$\text{m}\Omega$
		$V_{GS} = -4.5\text{V}, I_D = -15\text{A}$		22	30	
Forward Transconductance	$g_{FS}$	$V_{GS} = -5\text{V}, I_D = -20\text{A}$		25		S
<b>Dynamic Characteristics</b> <small>(Note 4)</small>						
Input Capacitance	$C_{iss}$	$V_{DS} = -15\text{V}, V_{GS} = 0\text{V}, f = 1\text{MHz}$		1363		$\text{pF}$
Output Capacitance	$C_{oss}$			250		
Reverse Transfer Capacitance	$C_{rss}$			210		
<b>Switching Characteristics</b> <small>(Note 4)</small>						
Turn-on Delay Time	$T_{d(on)}$	$V_{DD} = -30\text{V}, R_L = 3\Omega, V_{GS} = -10\text{V}, R_G = 2.5\Omega$		9		$\text{nS}$
Turn-on Rise Time	$T_r$			10		
Turn-off Delay Time	$T_{d(off)}$			50		
Turn-off Fall Time	$T_f$			20		
Total Gate Charge	$Q_g$	$V_{DS} = -15\text{V}, I_D = -15\text{A}, V_{GS} = -10\text{V},$		31.2		$\text{nC}$
Gate-Source Charge	$Q_{gs}$			3.2		
Gate-Drain Charge	$Q_{gd}$			9.2		
<b>Drain-Source Diode Characteristics</b>						
Diode Forward Voltage <small>(Note 3)</small>	$V_{SD}$	$I_S = -15\text{A}, V_{GS} = 0\text{V}$			-1.2	V
Reverse Recovery Time	$t_{rr}$	$T_J = 25^\circ\text{C}, I_F = -15\text{A}$		24		$\text{nS}$
Reverse Recovery Charge	$Q_{rr}$		$di/dt = -100\text{A}/\mu\text{s}$ <small>(Note 3)</small>	16		$\text{nC}$

### Note:

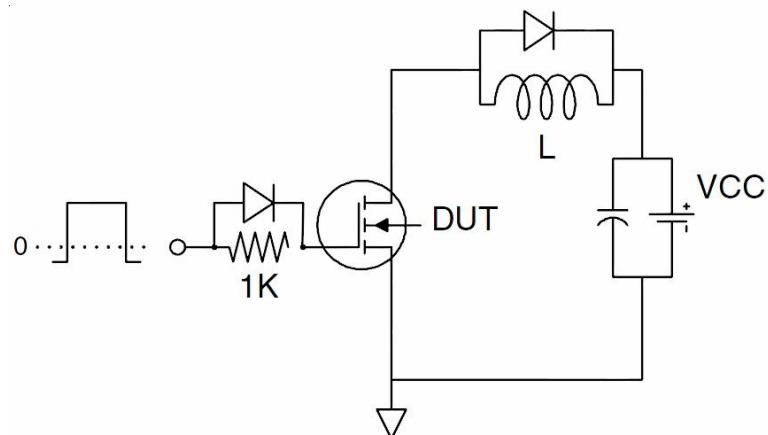
1. Repetitive Rating: Pulse width limited by maximum junction temperature.
2. Surface Mounted on FR4 Board,  $t \leq 10$  sec.
3. Pulse Test: Pulse Width  $\leq 300\mu\text{s}$ , Duty Cycle  $\leq 2\%$ .
4. Guaranteed by design, not subject to production
5. EAS condition:  $T_j = 25^\circ\text{C}, V_{DD} = 15\text{V}, V_G = 10\text{V}, L = 0.5\text{mH}, R_g = 25\Omega, I_{AS} = 26\text{A}$

## Test Circuits

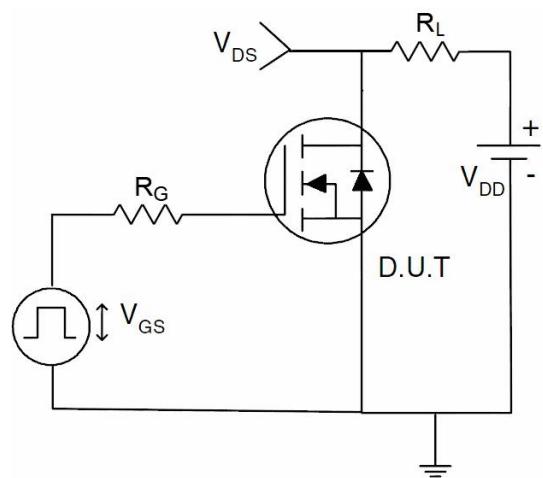
- EAS Test Circuits



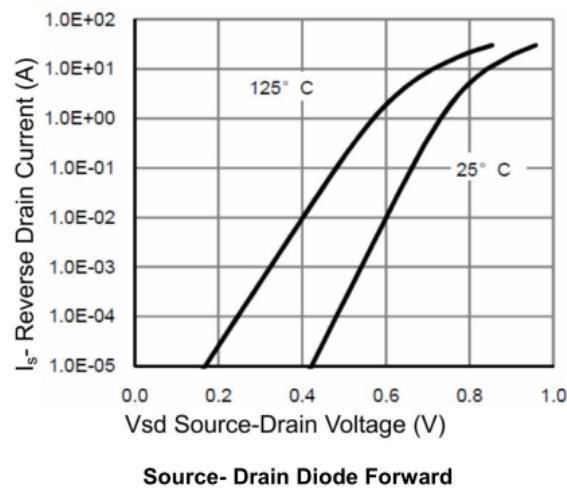
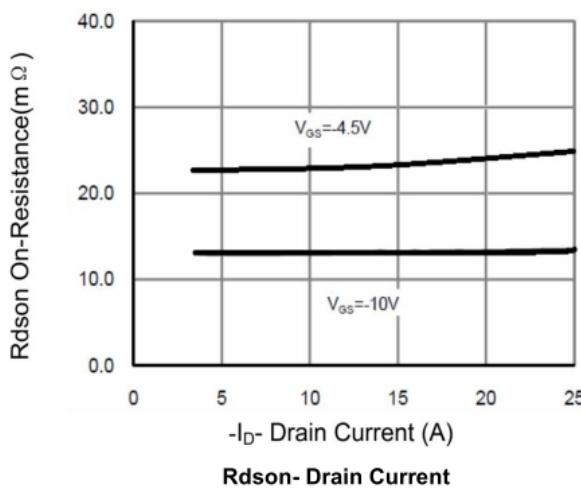
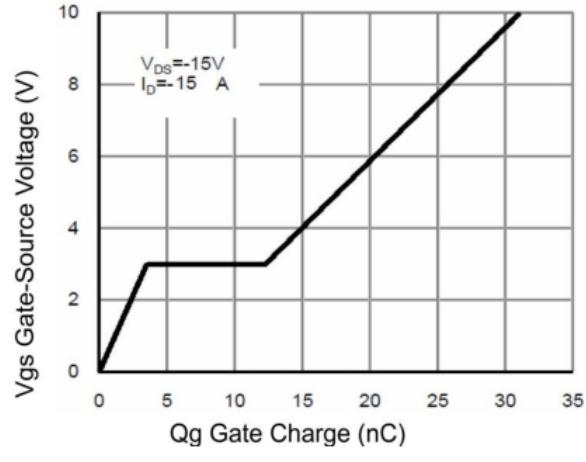
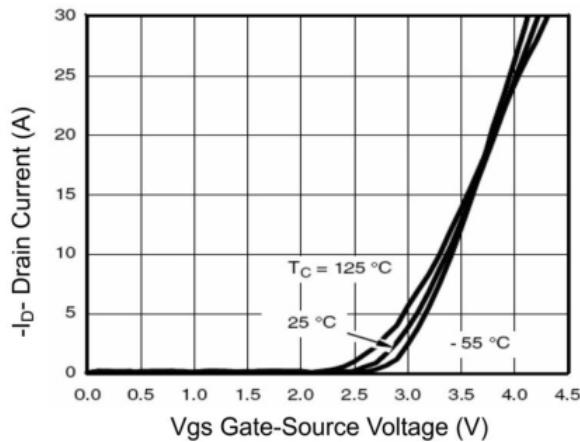
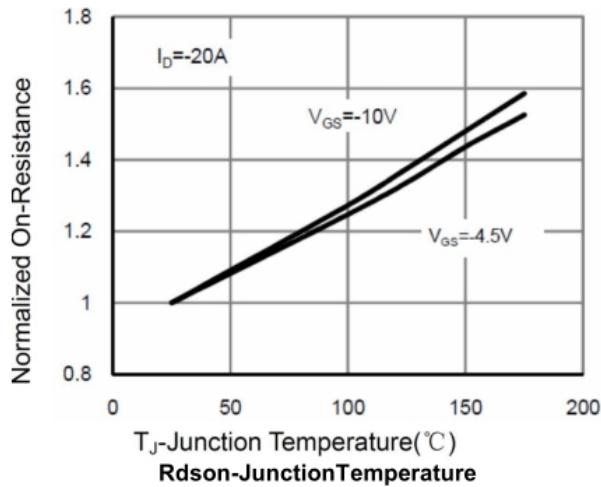
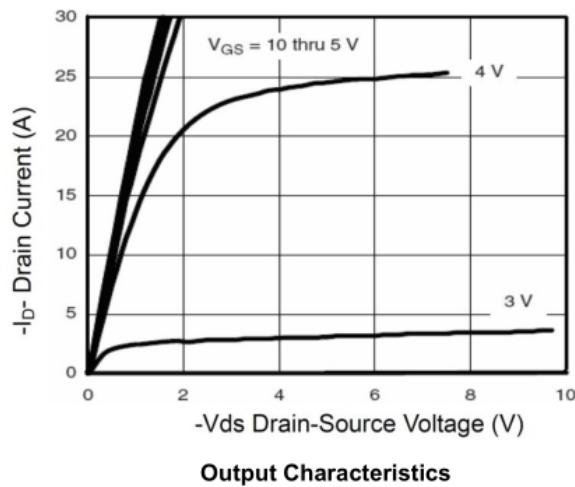
- Gate Charge Test Circuit

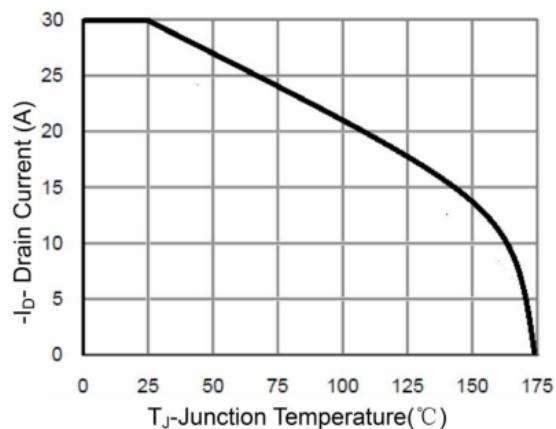
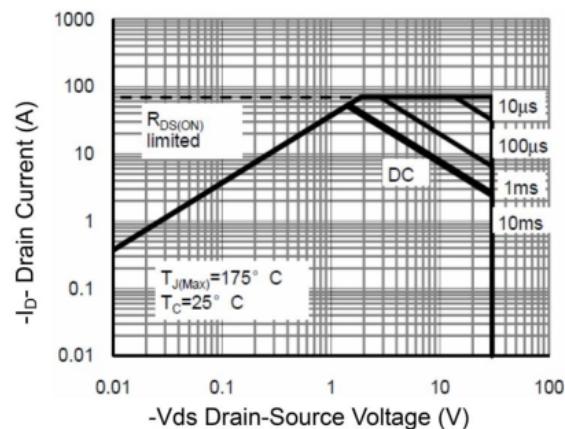
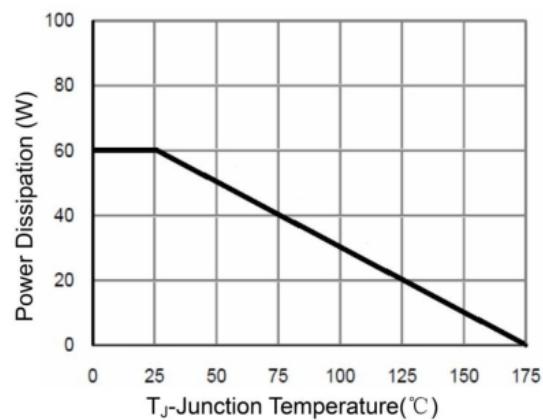
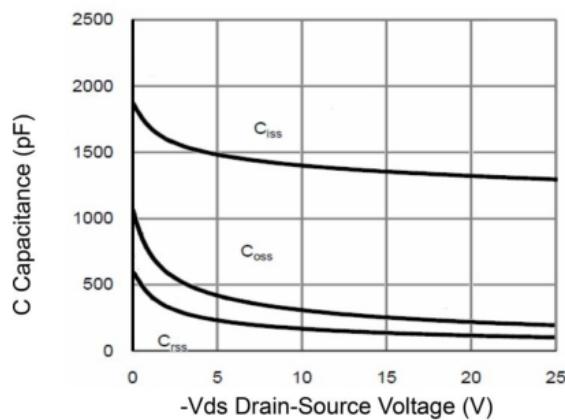


- Switch Time Test Circuit



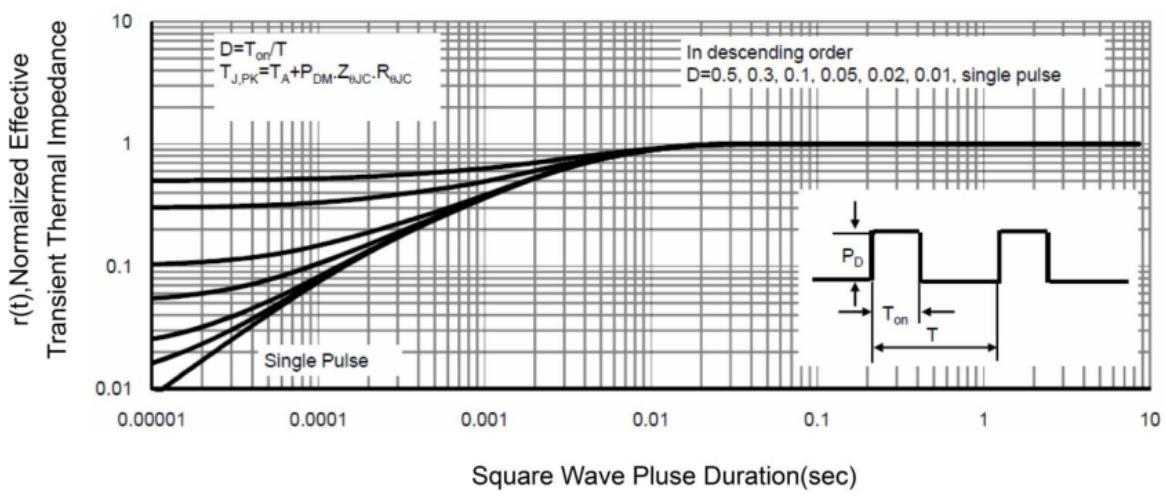
## Typical Characteristics





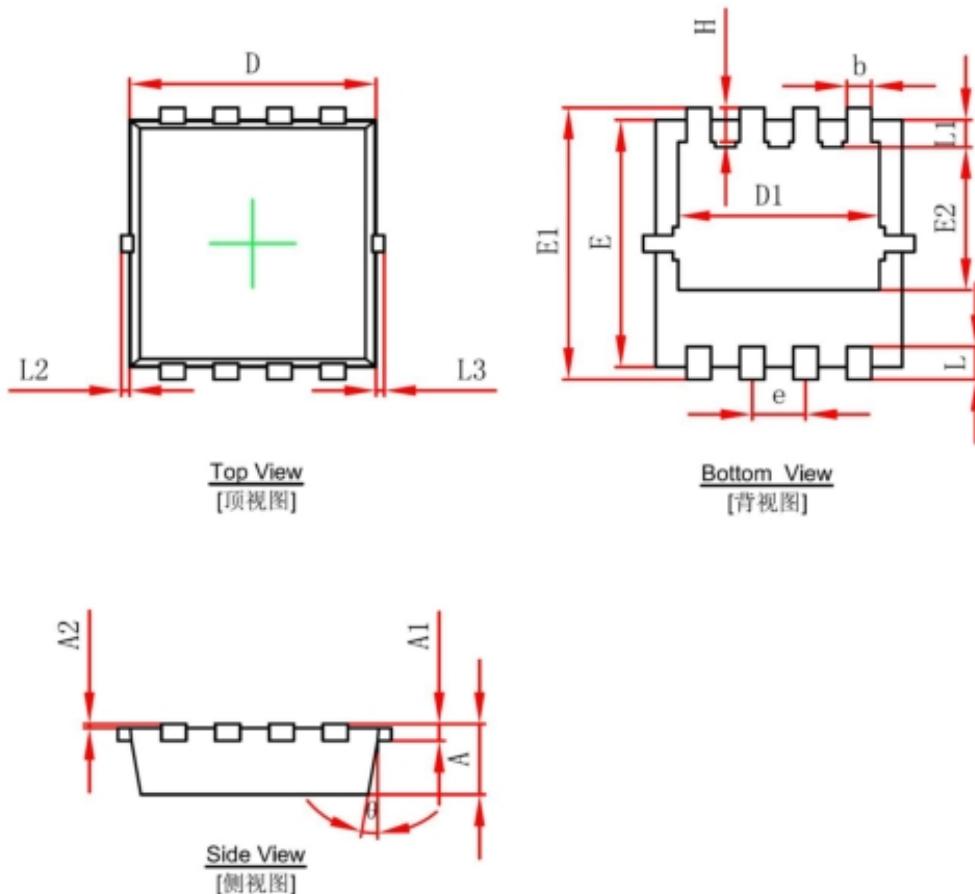
Safe Operation Area

ID Current Derating



Normalized Maximum Transient Thermal Impedance

## PDFNWB3.3×3.3-8L Package Information



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	0.650	0.850	0.026	0.033
A1	0.152 REF.			0.006 REF.
A2	0~0.05			0~0.002
D	2.900	3.100	0.114	0.122
D1	2.300	2.600	0.091	0.102
E	2.900	3.100	0.114	0.122
E1	3.150	3.450	0.124	0.136
E2	1.535	1.935	0.060	0.076
b	0.200	0.400	0.008	0.016
e	0.550	0.750	0.022	0.030
L	0.300	0.500	0.012	0.020
L1	0.180	0.480	0.007	0.019
L2	0~0.100			0~0.004
L3	0~0.100			0~0.004
H	0.315	0.515	0.012	0.020
$\theta$	9°	13°	9°	13°